DATA SHEET



HETERO JUNCTION FIELD EFFECT TRANSISTOR NE3510M04

L TO S BAND LOW NOISE AMPLIFIER N-CHANNEL HJ-FET

FEATURES

· Low noise figure and high associated gain

NF = 0.45 dB TYP., G_a = 16 dB TYP. @ f = 4 GHz, V_{DS} = 2 V, I_D = 15 mA NF = 0.35 dB TYP., G_a = 19 dB TYP. @ f = 2 GHz, V_{DS} = 2 V, I_D = 10 mA (Reference only)

• Flat-lead 4-pin thin-type super minimold (M04) package

APPLICATIONS

- Satellite radio (SDARS, DMB, etc.) antenna LNA
- · Low noise amplifier for microwave communication system

ORDERING INFORMATION

Part Number	Order Number	Package	Quantity	Marking	Supplying Form
NE3510M04	NE3510M04-A	Flat-lead 4-pin thin-	50 pcs (Non reel)	V81	8 mm wide embossed taping
NE3510M04-T2	NE3510M04-T2-A	type super minimold (M04) (Pb-Free)	3 kpcs/reel		• Pin 1 (Source), Pin 2 (Drain) face the perforation side of the tape

Remark To order evaluation samples, contact your nearby sales office.

Part number for sample order: NE3510M04

ABSOLUTE MAXIMUM RATINGS (TA = +25°C)

Parameter	Symbol	Ratings	Unit
Drain to Source Voltage	V _{DS}	4.0	V
Gate to Source Voltage	V _{GS}	-3.0	V
Drain Current	lσ	Ipss	mA
Gate Current	lg	140	μΑ
Total Power Dissipation	Ptot Note	125	mW
Channel Temperature	Tch	+150	°C
Storage Temperature	T _{stg}	−65 to +150	°C

Note Mounted on 1.08 cm² × 1.0 mm (t) glass epoxy PCB

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

Not all products and/or types are available in every country. Please check with an NEC Electronics sales representative for availability and additional information.

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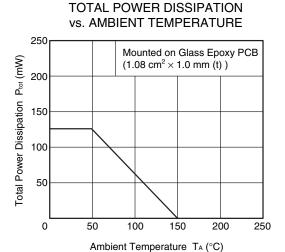
RECOMMENDED OPERATING CONDITIONS (TA = +25°C)

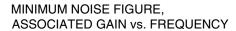
Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Drain to Source Voltage	VDS	ı	2	3	V
Drain Current	ΙD	-	15	30	mA
Input Power	Pin	-	_	0	dBm

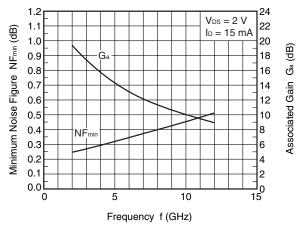
ELECTRICAL CHARACTERISTICS (TA = +25°C, unless otherwise specified)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Gate to Source Leak Current	Igso	V _{GS} = -3 V	-	0.5	10	μΑ
Saturated Drain Current	IDSS	V _{DS} = 2 V, V _{GS} = 0 V	42	70	97	mA
Gate to Source Cutoff Voltage	V _{GS} (off)	$V_{DS} = 2 \text{ V}, I_{D} = 100 \ \mu\text{A}$	-0.35	-0.7	-1.10	V
Transconductance	g _m	V _{DS} = 2 V, I _D = 15 mA	70	-	-	mS
Noise Figure	NF	V _{DS} = 2 V, I _D = 15 mA, f = 4 GHz	-	0.45	0.65	dB
Associated Gain	Ga		14.5	16	-	dB
Gain 1 dB Compression	Po (1 dB)	V _{DS} = 2 V, I _D = 15 mA (Non-RF),	-	+11	-	dBm
Output Power		f = 4 GHz				

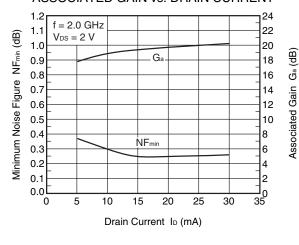
TYPICAL CHARACTERISTICS (TA = +25°C, unless otherwise specified)



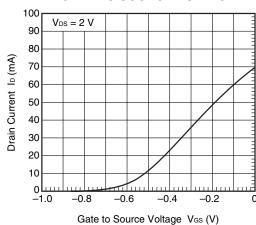




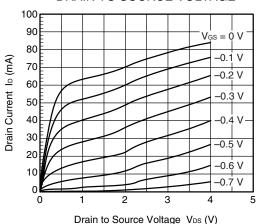
MINIMUM NOISE FIGURE, ASSOCIATED GAIN vs. DRAIN CURRENT



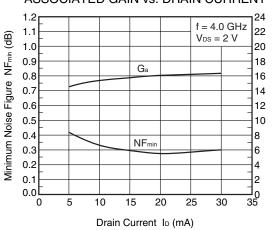
DRAIN CURRENT vs.
GATE TO SOURCE VOLTAGE



DRAIN CURRENT vs.
DRAIN TO SOURCE VOLTAGE



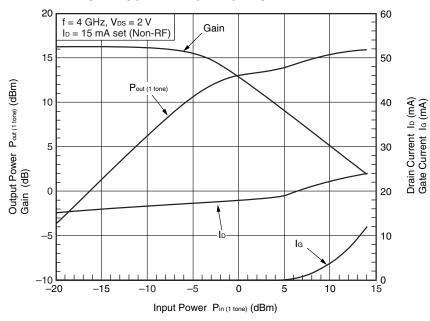
MINIMUM NOISE FIGURE, ASSOCIATED GAIN vs. DRAIN CURRENT



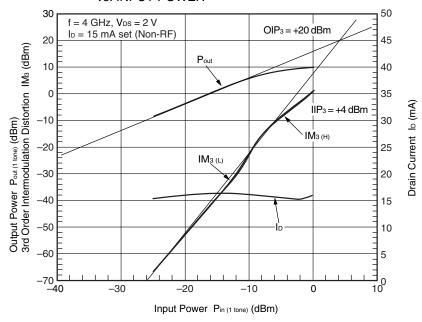
Remark The graphs indicate nominal characteristics.

Associated Gain Ga (dB)

OUTPUT POWER, GAIN, DRAIN CURRENT, GATE CURRENT vs. INPUT POWER



OUTPUT POWER, IM3, DRAIN CURRENT vs. INPUT POWER



Remark The graphs indicate nominal characteristics.

NEC NE3510M04

S-PARAMETERS

S-parameters/Noise parameters are provided on our web site in a form (S2P) that enables direct import to a microwave circuit simulator without keyboard input.

Click here to download S-parameters.

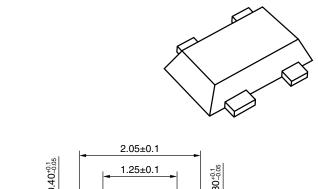
 $[\mathsf{RF} \ \mathsf{and} \ \mathsf{Microwave}] \to [\mathsf{Device} \ \mathsf{Parameters}]$

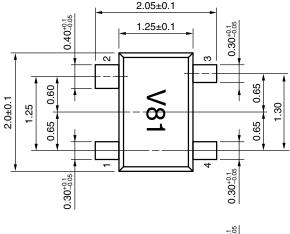
URL http://www.ncsd.necel.com/microwave/index.html

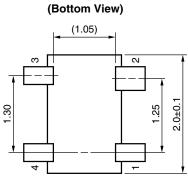
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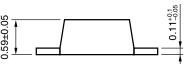
PACKAGE DIMENSIONS

FLAT-LEAD 4-PIN THIN-TYPE SUPER MINIMOLD (M04) (UNIT: mm)







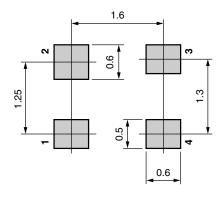


PIN CONNECTIONS

- 1. Source
- 2. Drain
- 3. Source
- 4. Gate

MOUNTING PAD DIMENSIONS (REFERENCE ONLY)

FLAT-LEAD 4-PIN THIN-TYPE SUPER MINIMOLD (M04) PACKAGE (UNIT: mm)





RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions	Condition Symbol	
Infrared Reflow	Peak temperature (package surface temperature) Time at peak temperature Time at temperature of 220°C or higher Preheating time at 120 to 180°C Maximum number of reflow processes Maximum chlorine content of rosin flux (% mass)	: 260°C or below : 10 seconds or less : 60 seconds or less : 120±30 seconds : 3 times : 0.2%(Wt.) or below	IR260
Partial Heating	Peak temperature (terminal temperature) Soldering time (per side of device) Maximum chlorine content of rosin flux (% mass)	: 350°C or below : 3 seconds or less : 0.2%(Wt.) or below	HS350

Caution Do not use different soldering methods together (except for partial heating).

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M8E 02.11-1



Caution

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
- Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.